International Rectifier

10WQ045FN

SCHOTTKY RECTIFIER

10 Amp



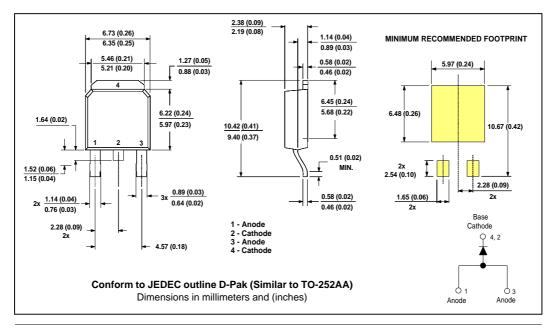
Major Ratings and Characteristics

Characteristics	10WQ045FN	Units
I _{F(AV)} Rectangular waveform	10	А
V _{RRM}	45	V
I _{FSM} @ tp=5 µs sine	400	А
V _F @10Apk,T _J =125°C	0.53	V
T _J range	-40 to 175	°C

Description/ Features

The 10WQ045FN surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, free-wheeling diodes, battery charging, and reverse battery protection.

- Popular D-PAK outline
- Small foot print, surface moutable
- · Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability



10WQ045FN

Bulletin PD-20530 rev. F 03/03

International TOR Rectifier

Voltage Ratings

Part number	10WQ045FN		
V _R Max. DC Reverse Voltage (V)	45		
V _{RWM} Max. Working Peak Reverse Voltage (V)			

Absolute Maximum Ratings

	Parameters	10WQ	Units	Conditions		
I _{F(AV)}	Max. Average Forward Current *See Fig. 5	10	А	50% duty cycle @ T _C =157°C, rectangular wave form		
I _{FSM}	Max.PeakOneCycleNon-Repet.	400	Α	5μs Sine or 3μs Rect. pulse	Following any rated load condition and with	
	Surge Current *See Fig. 7	75 A		10ms Sine or 6ms Rect. pulse	rated V _{RRM} applied	
E _{AS}	Non-RepetitiveAvalancheEnergy	20	mJ	T _J = 25 °C, I _{AS} = 3.0 Amps, L = 4.40 mH		
I _{AR}	Repetitive Avalanche Current	3.0	А	Current decaying linearly to zero in 1 μ sec Frequency limited by T_J max. V_A = 1.5 μ x V _R typical		

Electrical Specifications

Parameters		10WQ	Units	Conditions			
V _{FM}	Max. Forward Voltage Drop		0.630	V	@ 10A	T _J = 25 °C	
	* See Fig. 1	(1)	0.800	V	@ 20A	-	
			0.530	V	@ 10A	T _J = 125 °C	
			0.710	V	@ 20A		
I _{RM}	Max. Reverse Leakage	Current	1	mA	T _J = 25 °C	$V_R = \text{rated } V_R$	
	* See Fig. 2	(1)	15	mA	T _J = 125 °C		
V _{F(TO}	Threshold Voltage		0.255	V	$T_J = T_J \text{ max.}$		
r _t	Forward Slope Resista	ınce	22	mΩ			
Ст	Typical Junction Capac	citance	760	pF	V _R = 5V _{DC} (test signal range 100Khz to 1Mhz) 25 °C		
L _S	Typical Series Inductar	nce	5.0	nH	Measured lead to lead 5mm from package body		

⁽¹⁾ Pulse Width < 300 μ s, Duty Cycle < 2%

Thermal-Mechanical Specifications

	Parameters	10WQ	Units	Conditions	
T _J	Max.JunctionTemp.Range(*)	- 40 to 175	°C		
T _{stg}	Max. Storage Temperature Range	- 40 to 175	°C		
R _{thJC}	Max. Thermal Resistance Junction to Case	2.0	°C/W	DCoperation	*See Fig. 4
R _{thJA}	Max. Thermal Resistance Junction to Ambient	50	°C/W		
wt	Approximate Weight	0.3(0.01)	g(oz.)		
	CaseStyle	D-PAK		Similar to TO-252AA	

 $[\]frac{\text{(*)}}{\text{dTj}} < \frac{\text{dPtot}}{\text{Rth(j-a)}} < \frac{1}{\text{Rth(j-a)}} \quad \text{thermal runaway condition for a diode on its own heatsink}$

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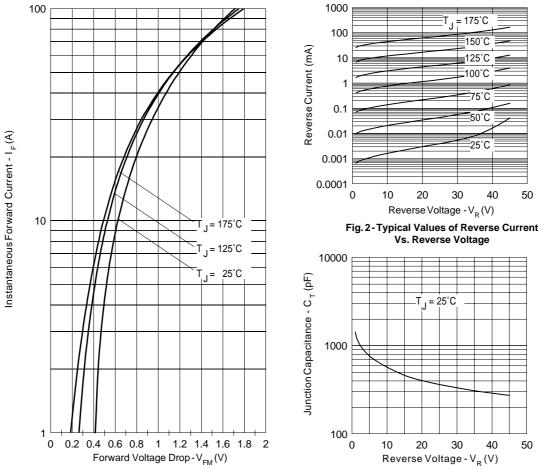


Fig. 1 - Maximum Forward Voltage Drop Characteristics

Fig. 3-Typical Junction Capacitance Vs. Reverse Voltage

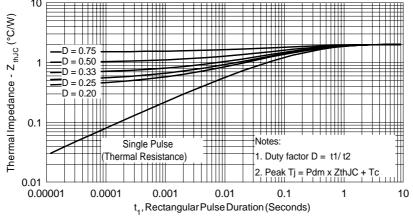


Fig. 4-Maximum Thermal Impedance Z_{thJC} Characteristics

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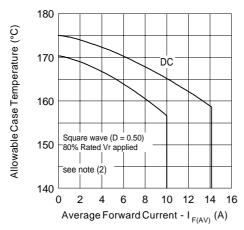


Fig. 5 - Maximum Allowable Case Temperature Vs. Average Forward Current

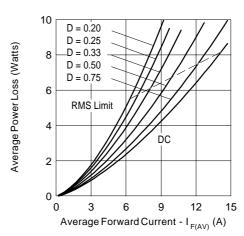


Fig. 6-Forward Power Loss Characteristics

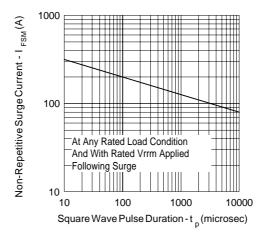
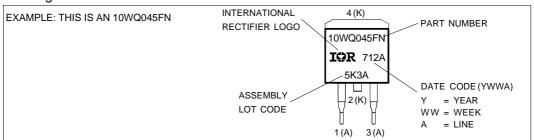
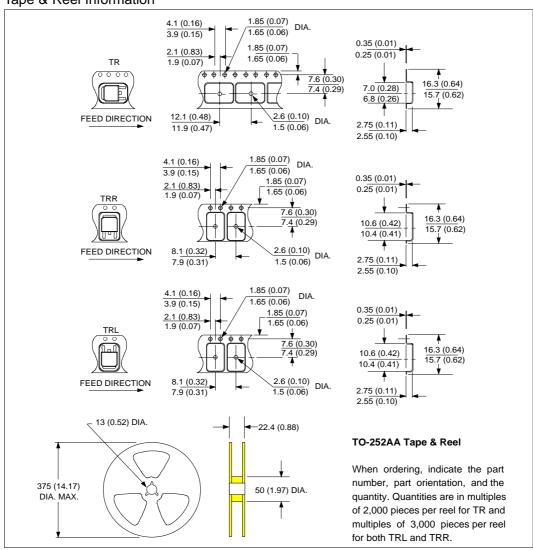


Fig. 7 - Maximum Non-Repetitive Surge Current

Marking Information



Tape & Reel Information



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Data and specifications subject to change without notice. This product has been designed and qualified for Industrial Level.

Qualification Standards can be found on IR's Web site.



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